TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74LVX02F,TC74LVX02FN,TC74LVX02FT

### Quad 2-Input NOR Gate

The TC74LVX02F/ FN/ FT is a high-speed CMOS 2-input NOR gate fabricated with silicon gate CMOS technology. Designed for use in 3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

This device is suitable for low-voltage and battery operated systems.

The internal circuit is composed of 3 stages including buffer output, which provide high noise immunity and stable output.

An input protection circuit ensures that 0 to 5.5V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

#### **Features**

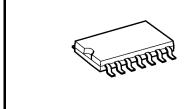
- High-speed:  $t_{pd} = 4.5 \text{ ns (typ.)} (V_{CC} = 3.3 \text{ V})$
- Low-power dissipation:  $I_{CC} = 2 \mu A \text{ (max) (Ta} = 25 ^{\circ}\text{C)}$
- Input voltage level:  $V_{IL} = 0.8 \text{ V (max)} (V_{CC} = 3 \text{ V})$

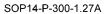
$$V_{IH} = 2.0 \text{ V (min)} (V_{CC} = 3 \text{ V})$$

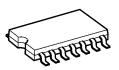
- Power-down protection provided on all inputs
- Balanced propagation delays: tpLH ~ tpHL
- Low noise: VOLP = 0.5 V (max)
- Pin and function compatible with 74HC02

Note: xxxFN (JEDEC SOP) is not available in Japan.

TC74LVX02F







SOP14-P-300-1.27

TC74LVX02FN



SOL14-P-150-1.27

TC74LVX02FT



TSSOP14-P-0044-0.65A

Weight

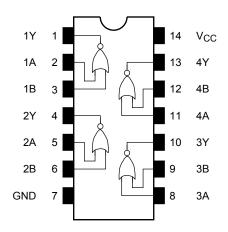
 SOP14-P-300-1.27A
 : 0.18 g (typ.)

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 : 0.18 g (typ.)

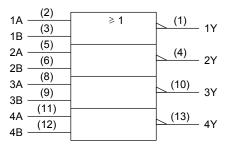
 SOL14-P-150-1.27
 : 0.12 g (typ.)

 TSSOP14-P-0044-0.65A
 : 0.06 g (typ.)

# Pin Assignment (top view)



# **IEC Logic Symbol**



### **Truth Table**

Inp	Outputs		
Α	В	Υ	
L	L	Н	
L	Н	L	
Н	L	L	
Н	Н	L	

# **Absolute Maximum Ratings (Note)**

Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	-0.5 to 7.0	V
DC input voltage	V <sub>IN</sub>	-0.5 to 7.0	V
DC output voltage	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	I <sub>IK</sub>	-20	mA
Output diode current	lok	±20	mA
DC output current	lout	±25	mA
DC V <sub>CC</sub> /ground current	Icc	±50	mA
Power dissipation	PD	180	mW
Storage temperature	T <sub>stg</sub>	-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.



# **Recommended Operating Conditions (Note)**

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	2.0 to 3.6	V
Input voltage	V <sub>IN</sub>	0 to 5.5	V
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 100	ns/V

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

### **Electrical Characteristics**

#### **DC Characteristics**

Characteristics Symbol Test Condition		Condition		Ta = 25°C			Ta = -40 to 85°C		Unit			
					V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max		
			_		2.0	1.5	_	_	1.5	_		
	H-level	V <sub>IH</sub>		_	3.0	2.0	_	_	2.0			
Input voltage	Input voltage				3.6	2.4	_	_	2.4	_	V	
input voltage	input voitage				2.0	_	_	0.5	_	0.5		
	L-level	V <sub>IL</sub>		_	3.0	_	_	0.8	_	0.8		
					3.6	_	_	0.8	_	0.8		
	H-level V <sub>OH</sub>		$I_{OH} = -50 \mu A$	2.0	1.9	2.0	_	1.9	_			
		VoH	$V_{IN} = V_{IL}$	I <sub>OH</sub> = -50 μA	3.0	2.9	3.0	_	2.9	_		
Output voltage				I <sub>OH</sub> = -4 mA	3.0	2.58	_	_	2.48	_	V	
Output voitage	Output voltage	L-level V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	2.0	_	0	0.1	_	0.1	V	
L-level	L-level			I <sub>OL</sub> = 50 μA	3.0	_	0	0.1	_	0.1		
				I <sub>OL</sub> = 4 mA	3.0	_	_	0.36	_	0.44		
Input leakage cur	rent	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		3.6	_		±0.1	_	±1.0	μА	
Quiescent supply	current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		3.6			2.0	_	20.0	μΑ	



### AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$ )

Characteristics	Symbol	Symbol Test Condition				Ta = 25°C			Ta = -40 to 85°C	
			V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Тур.	Max	Min	Max	
Propagation delay time	t <sub>pLH</sub>	_	2.7	15	_	5.9	10.7	1.0	13.5	- ns
				50	_	8.4	14.2	1.0	17.0	
	t <sub>pHL</sub>		3.3 ± 0.3	15	_	4.5	6.6	1.0	8.0	
				50	_	7.0	10.1	1.0	11.5	
Output to output skew	t <sub>osLH</sub>	(Note 1)	2.7	50	_	_	1.5	_	1.5	ns
	t <sub>osHL</sub>	(Note 1)	$3.3 \pm 0.3$	50	_	_	1.5	_	1.5	115
Input capacitance	C <sub>IN</sub>			(Note 2)		4	10		10	pF
Power dissipation capacitance	C <sub>PD</sub>			(Note 3)		15	_	_		pF

Note 1: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{pLHm} - t_{pLHn}|, t_{OSHL} = |t_{pHLm} - t_{pHLn}|)$ 

Note 2: Parameter guaranteed by design.

Note 3: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

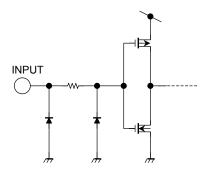
Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4 \text{ (per gate)}$ 

#### Noise Characteristics (Ta = 25°C, input: $t_r = t_f = 3$ ns, $C_L = 50$ pF)

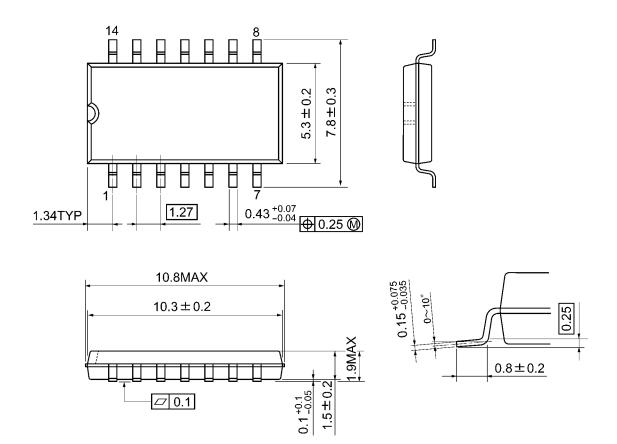
Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Limit	Unit
Quiet output maximum dynamic V <sub>OL</sub>	V <sub>OLP</sub>	_	3.3	0.3	0.5	V
Quiet output minimum dynamic V <sub>OL</sub>	V <sub>OLV</sub>	_	3.3	-0.3	-0.5	V
Minimum high level dynamic input voltage V <sub>IH</sub>	V <sub>IHD</sub>	_	3.3	_	2.0	V
Maximum low level dynamic input voltage V <sub>IL</sub>	V <sub>ILD</sub>	_	3.3	_	0.8	٧

### **Input Equivalent Circuit**



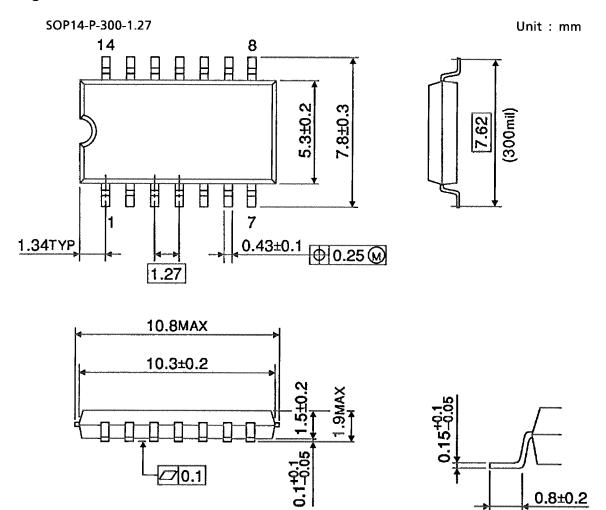
# **Package Dimensions**

SOP14-P-300-1.27A Unit: mm



Weight: 0.18 g (typ.)

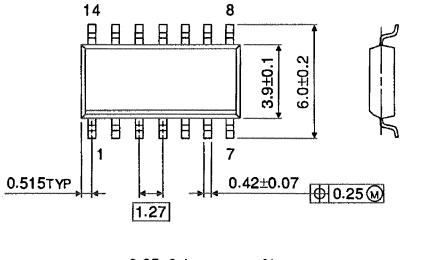
### **Package Dimensions**

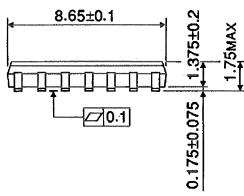


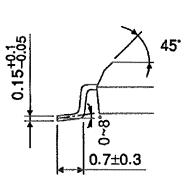
Weight: 0.18 g (typ.)

# **Package Dimensions (Note)**

SOL14-P-150-1.27 Unit: mm







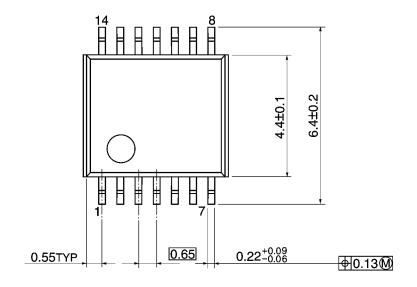
Note: This package is not available in Japan.

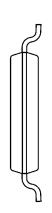
Weight: 0.12 g (typ.)

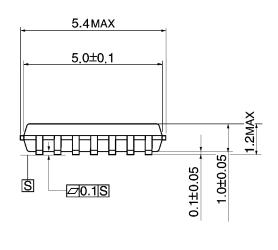
# **Package Dimensions**

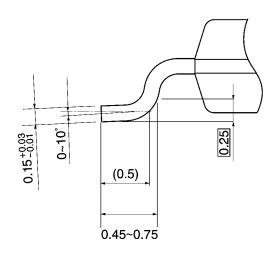
TSSOP14-P-0044-0.65A

Unit: mm









Weight: 0.06 g (typ.)

Note: Lead (Pb)-Free Packages

SOP14-P-300-1.27A SOL14-P-150-1.27 TSSOP14-P-0044-0.65A

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